

0.9 V to 2.5 V, 66 mΩ Load Switch in TDFN4

DESCRIPTION

The SiP32501 is a compact, low R_{ON} turn on slew rate controlled load switch. The device has 66 mΩ resistance and operates over the input voltage range of 0.9 V to 2.5 V without requirement of extra bias power rail.

The SiP32501 has low input logic control threshold that can interface with low voltage control GPIO directly without extra level shift or driver. The switch supports designs when control logic voltage is higher than input power voltage. There is a pull down at this EN logic control pin.

The SiP32501 has 20 μs typically for input voltage of 1.2 V. Its turn off delay time is less than 1 μs. An output discharge switch is integrated.

SiP32501 is available in small TDFN4 package of 1.2 mm x 1.6 mm x 0.55 mm. The device is designed for the operation temperature range of -40 °C to +85 °C.

FEATURES

- Low input voltage, 0.9 V to 2.5 V
- Low R_{ON} , 66 mΩ typical
- Fast turn on time
- Low quiescent current
- Low logic control with hysteresis
- Reverse current blocking when disabled
- Integrated pull down at EN pin
- Output discharge
- TDFN4 1.2 mm x 1.6 mm
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

APPLICATIONS

- Battery operated devices
- Smartphones and tablet
- Ultrabook and notebook
- Portable industrial equipment
- Medical and healthcare equipment
- Digital cameras
- Game console

TYPICAL APPLICATION CIRCUIT

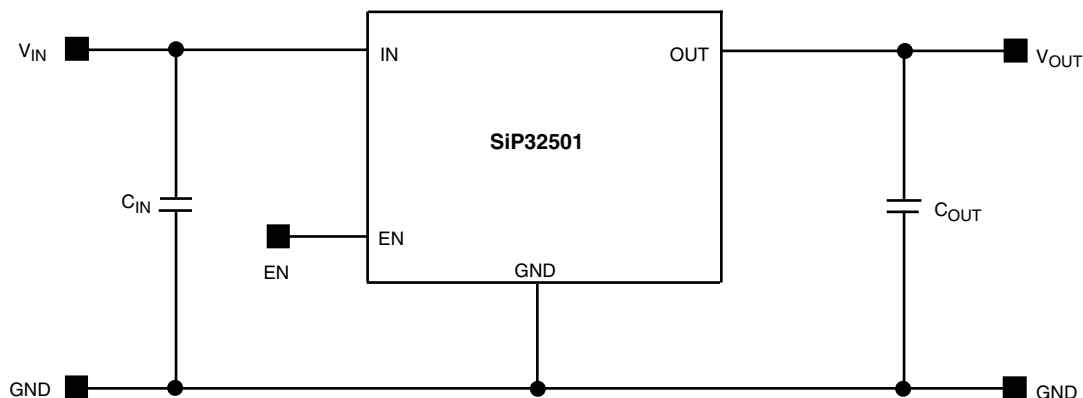


Fig. 1 - SiP32501 Typical Application Circuit

ORDERING INFORMATION

TEMPERATURE RANGE	PACKAGE	MARKING	PART NUMBER
-40 °C to +85 °C	TDFN4 1.2 mm x 1.6 mm	Ux	SiP32501DNP-T1-GE4

Note

- -GE4 denotes halogen-free and RoHS-compliant

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	LIMIT	UNIT
Supply input voltage (V_{IN})	-0.3 to 2.75	V
Enable input voltage (V_{EN})	-0.3 to 2.75	
Output voltage (V_{OUT})	-0.3 to 2.75	
Maximum continuous switch current (I_{max})	1.2	A
Maximum pulsed current (I_{DM}) V_{IN} (pulsed at 1 ms, 10 % duty cycle)	2	
ESD rating (HBM)	4000	V
Junction temperature (T_J)	-40 to +150	°C
Thermal resistance (θ_{JA}) ^a	170	°C/W
Power dissipation (P_D) ^a	735	mW

Notes

- a. Device mounted with all leads and power pad soldered or welded to PC board
b. Derate 5.9 mW/°C above $T_A = 25\text{ °C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE

PARAMETER	LIMIT	UNIT
Input voltage range (V_{IN})	0.9 to 2.5	V
Operating junction temperature range	-40 to +125	°C

SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED $V_{IN} = 1\text{ V}$, $T_A = -40\text{ °C}$ to $+85\text{ °C}$ (Typical values are at $T_A = 25\text{ °C}$)	LIMITS			UNIT
			MIN. ^a	TYP. ^b	MAX. ^a	
Operating voltage ^c	V_{IN}		0.9	-	2.5	V
Quiescent current	I_Q	$V_{IN} = 1.2\text{ V}$, $V_{EN} = V_{IN}$, OUT = open	-	10	15	μA
		$V_{IN} = 2.5\text{ V}$, $V_{EN} = V_{IN}$, OUT = open	-	34	60	
Off supply current	$I_{Q(off)}$	EN = GND, OUT = open	-	-	30	
Off switch current	$I_{DS(off)}$	EN = GND, OUT = 0 V	-	-	30	
Reverse blocking current	I_{RB}	$V_{OUT} = 2.5\text{ V}$, $V_{IN} = 0.9\text{ V}$, $V_{EN} = 0\text{ V}$	-	0.001	10	m Ω
On resistance	$R_{DS(on)}$	$V_{IN} = 1\text{ V}$, $I_L = 200\text{ mA}$, $T_A = 25\text{ °C}$	-	69	82	
		$V_{IN} = 1.2\text{ V}$, $I_L = 200\text{ mA}$, $T_A = 25\text{ °C}$	-	68	82	
		$V_{IN} = 1.8\text{ V}$, $I_L = 200\text{ mA}$, $T_A = 25\text{ °C}$	-	66	80	
		$V_{IN} = 2.5\text{ V}$, $I_L = 200\text{ mA}$, $T_A = 25\text{ °C}$	-	66	80	
On resistance temp. coefficient	TC_{RDS}		-	4100	-	ppm/°C
Output pulldown resistance	R_{PD}	$V_{EN} = 0\text{ V}$, $T_A = 25\text{ °C}$	-	425	550	Ω
EN input low voltage ^c	V_{IL}	$V_{IN} = 1\text{ V}$	-	-	0.1	V
EN input high voltage ^c	V_{IH}	$V_{IN} = 2.5\text{ V}$	1.5	-	-	
EN input leakage	I_{EN}	$V_{IN} = 2.5\text{ V}$, $V_{EN} = 0\text{ V}$	-	-	1	μA
		$V_{IN} = 2.5\text{ V}$, $V_{EN} = 2.5\text{ V}$	-	10	15	
Output turn-on delay time	$t_{d(on)}$	$V_{IN} = 1.2\text{ V}$	-	0.4	1	μs
		$V_{IN} = 2.5\text{ V}$	-	0.05	1	
Output turn-on rise time	t_r	$V_{IN} = 1.2\text{ V}$	10	20	30	
		$V_{IN} = 2.5\text{ V}$	5	9.8	20	
Output turn-off delay time	$t_{d(off)}$	$V_{IN} = 1.2\text{ V}$	-	0.25	1	
		$V_{IN} = 2.5\text{ V}$	-	0.15	1	

Notes

- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
c. For V_{IN} outside this range consult typical EN threshold curve.

PIN CONFIGURATION

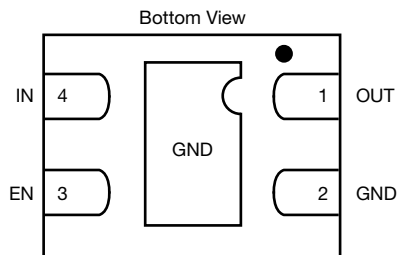


Fig. 2 - TDFN4 1.2 mm x 1.6 mm

PIN DESCRIPTION		
PIN NUMBER	NAME	FUNCTION
1	OUT	This pin is the n-channel MOSFET source connection. Bypass to ground through a 0.1 μ F capacitor
2	GND	Ground connection
3	EN	Enable input
4	IN	This pin is the n-channel MOSFET drain connection. Bypass to ground through a 4.7 μ F capacitor

BLOCK DIAGRAM

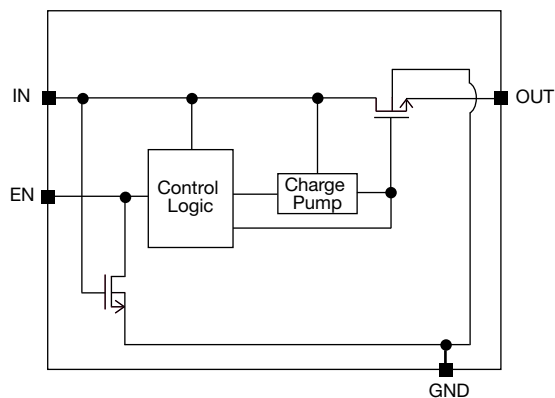
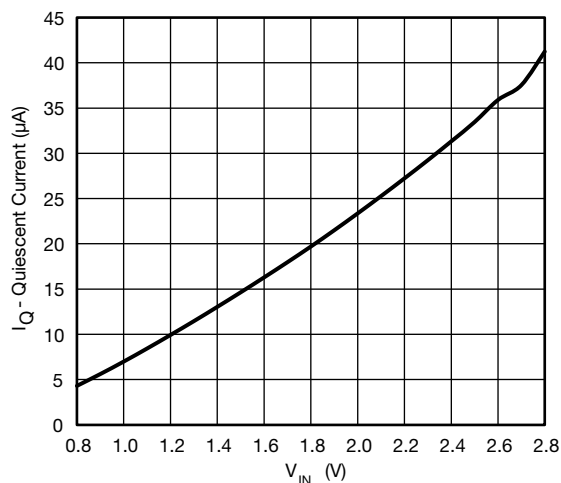
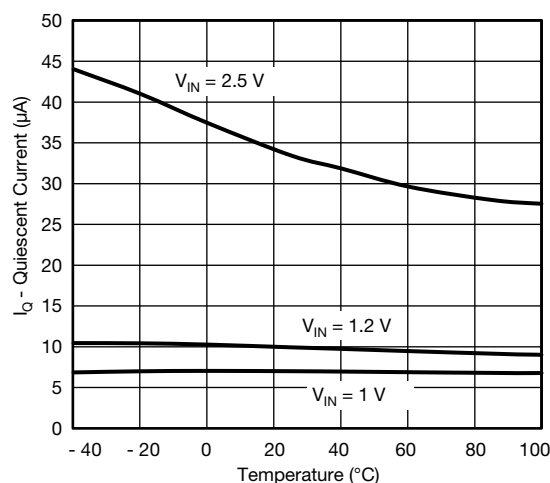
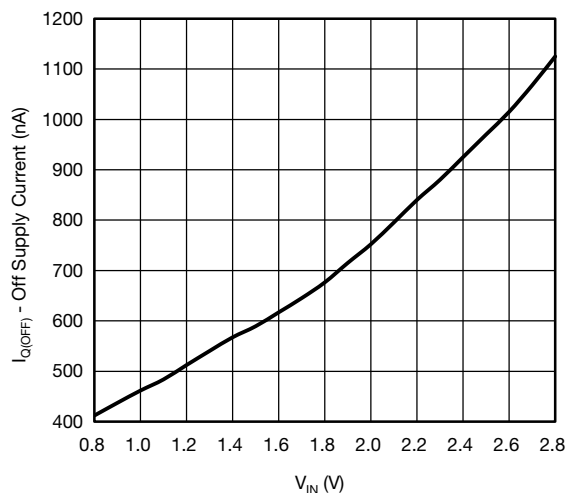
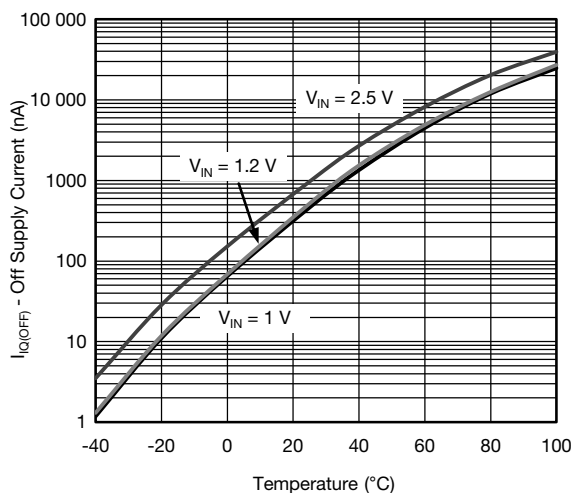
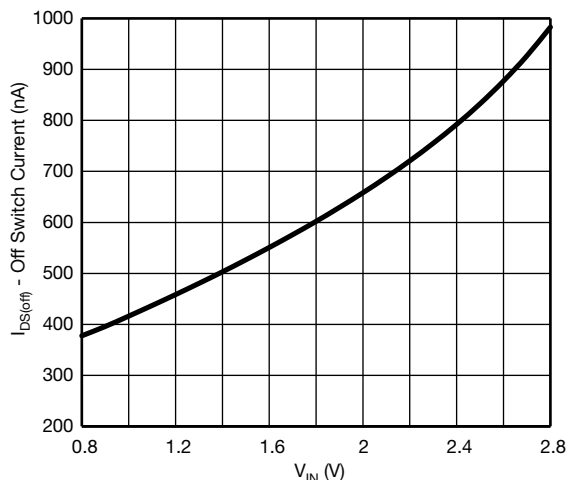
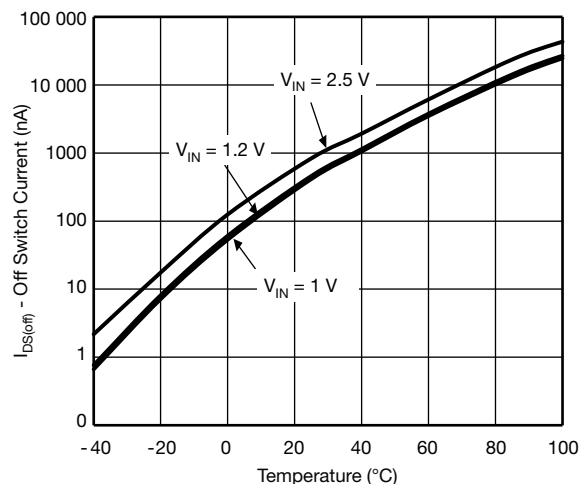
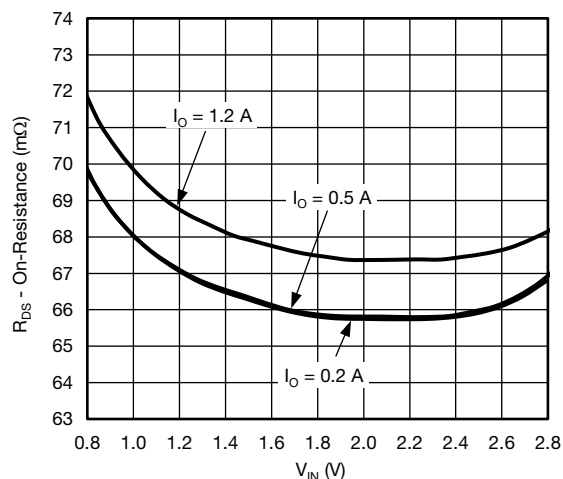
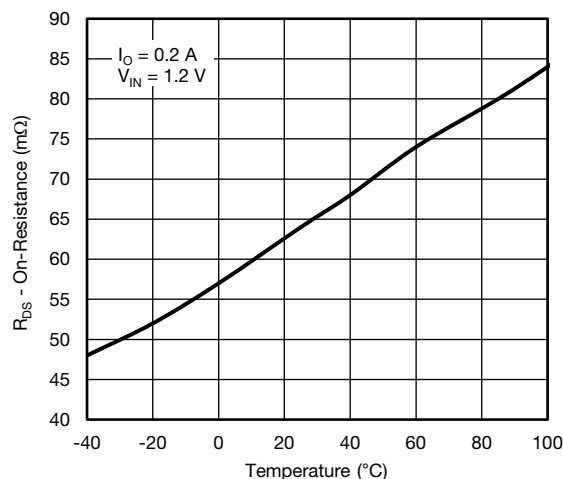
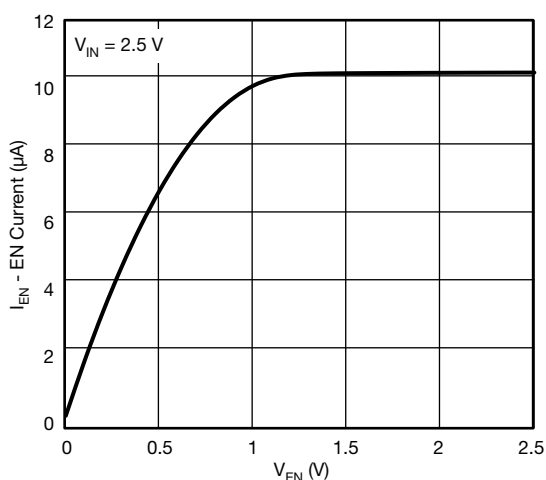
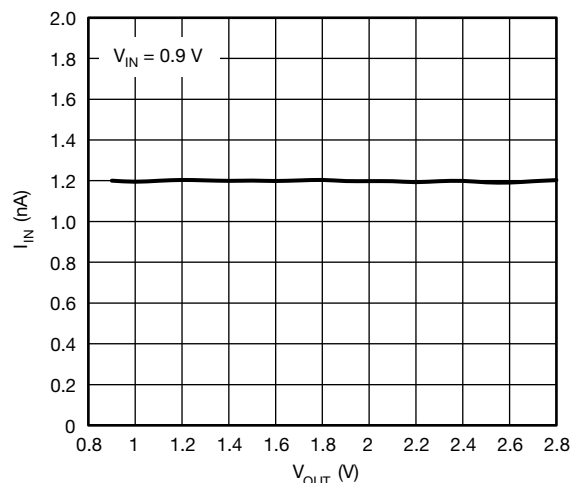
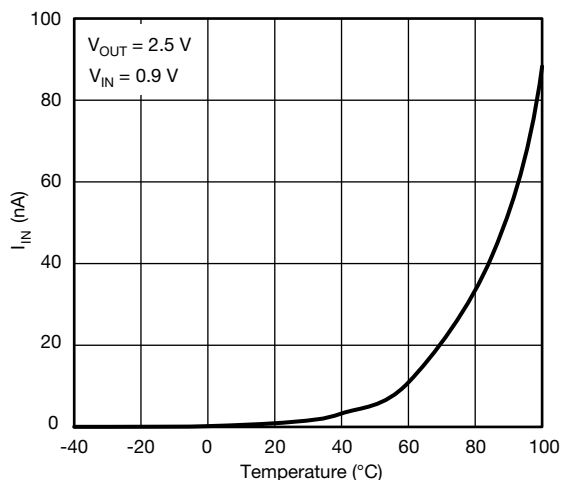
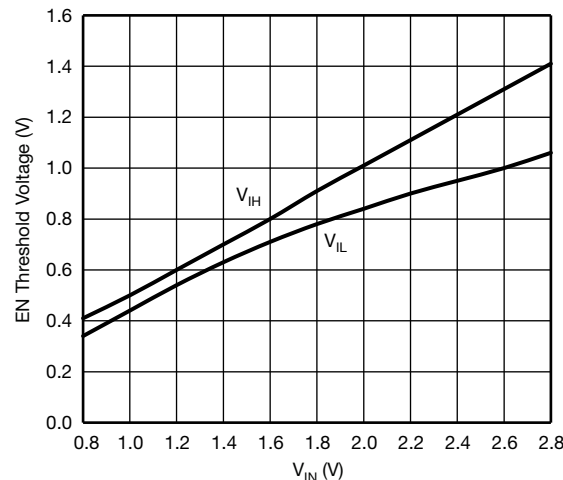
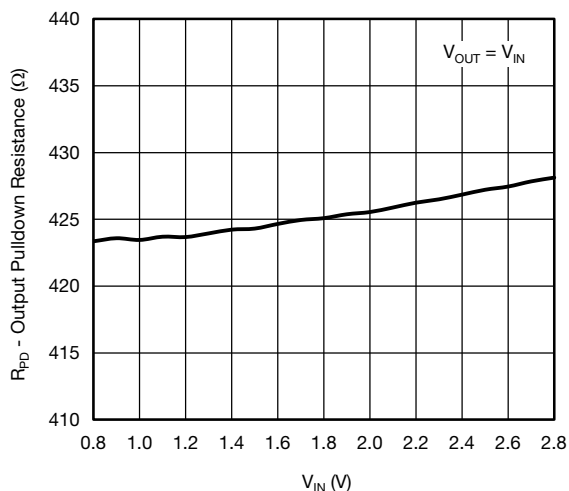
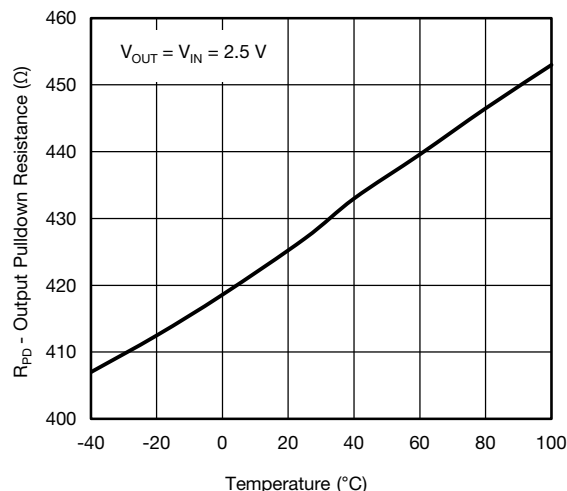
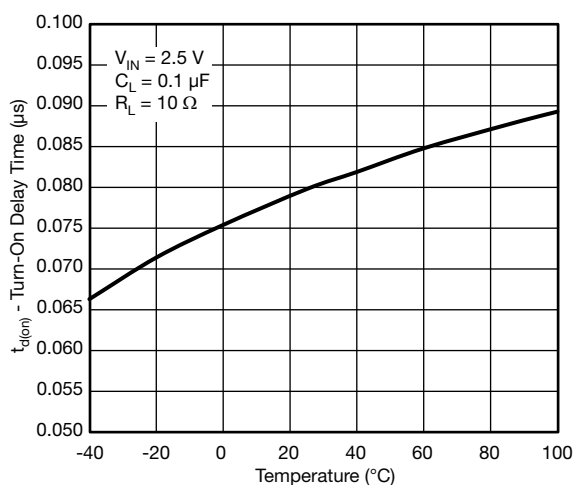
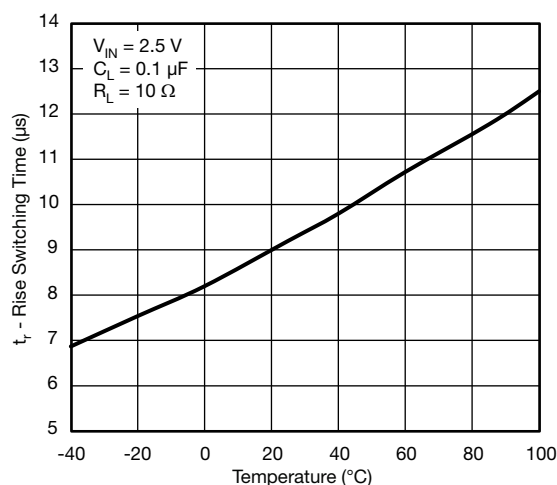
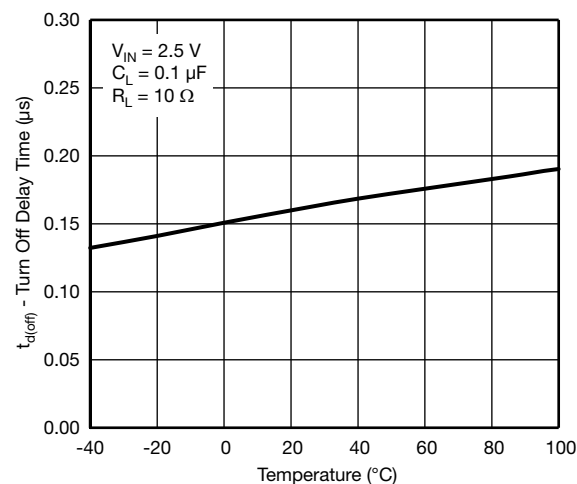


Fig. 3 - Functional Block Diagram

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

Fig. 4 - Quiescent Current vs. Input Voltage

Fig. 7 - Quiescent Current vs. Temperature

Fig. 5 - Off Supply Current vs. Input Voltage

Fig. 8 - Off Supply Current vs. Temperature

Fig. 6 - Off Switch Current vs. Input Voltage

Fig. 9 - Off Switch Current vs. Temperature

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

Fig. 10 - $R_{DS(on)}$ vs. V_{IN}

Fig. 13 - $R_{DS(on)}$ vs. Temperature

Fig. 11 - I_{EN} vs. V_{EN}

Fig. 14 - Reverse Blocking Current vs. Output Voltage

Fig. 12 - Reverse Blocking Current vs. Temperature

Fig. 15 - EN Threshold Voltage vs. Input Voltage

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

Fig. 16 - Output Pulldown Resistance vs. Input Voltage

Fig. 19 - Output Pulldown Resistance vs. Temperature

Fig. 17 - Turn-On Delay Time vs. Temperature

Fig. 20 - Rise Time vs. Temperature

Fig. 18 - Turn-Off Delay Time vs. Temperature



TYPICAL WAVEFORMS

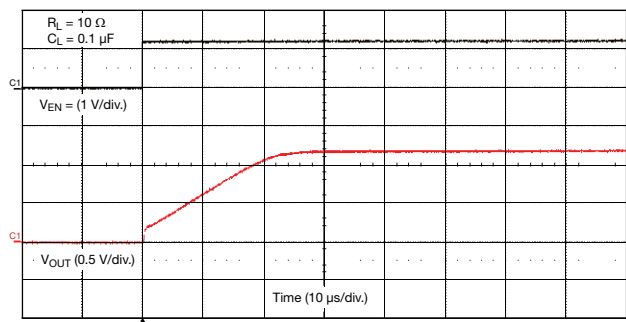


Fig. 21 - Turn-On Time ($V_{IN} = 1.2\text{ V}$)

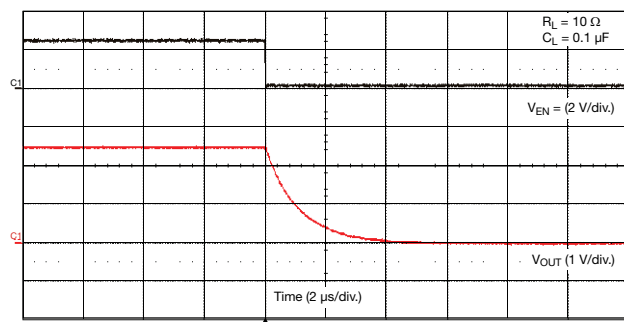


Fig. 24 - Turn-Off Time ($V_{IN} = 2.5\text{ V}$)

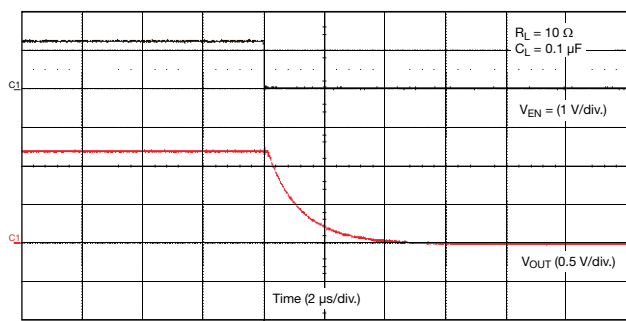


Fig. 22 - Turn-Off Time ($V_{IN} = 1.2\text{ V}$)

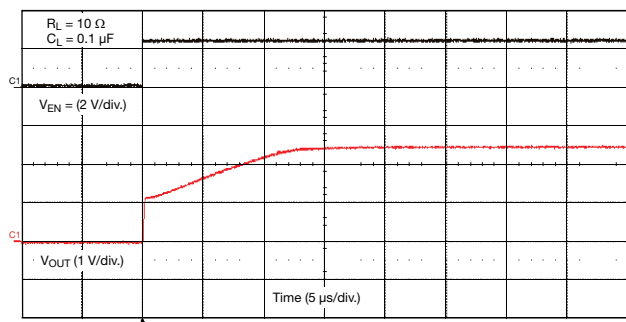


Fig. 23 - Turn-On Time ($V_{IN} = 2.5\text{ V}$)



DETAILED DESCRIPTION

The SiP32501 is a compact, low R_{ON} turn on slew rate controlled load switch. The device has 66 m Ω resistance and operates over the input voltage range of 0.9 V to 2.5 V without requirement of extra bias power rail.

The SiP32501 consisted of an n-channel power MOSFET designed as high side load switch. Once enabled the device charge pumps the gate of the power MOSFET to a constant gate to source voltage for fast turn on time. The mostly constant gate to source voltage keeps the on resistance low through the input voltage range.

The SiP32501 features an output discharge circuit to help discharge the output capacitor. Because the body of the output n-channel is always connected to GND, it prevents the current from going back to the input in case the output voltage is higher than the input.

The SiP32501 has low input logic control threshold that can interface with low voltage control GPIO directly without extra level shift or driver. The switch supports designs when control logic voltage is higher than input power voltage. There is a pull down at this EN logic control pin.

The SiP32501 has 20 μ s typically for input voltage of 1.2 V. Its turn off delay time is less than 1 μ s. An output discharge switch is integrated.

APPLICATION INFORMATION

Input Capacitor

While a bypass capacitor on the input is not required, to minimize the voltage drop on the input supply caused by load transient, a C_{IN} is recommended to be placed close to IN pin. A ceramic capacitor is recommended because of their ability to withstand current surges.

Output Capacitor

A 0.1 μ F capacitor across V_{OUT} and GND is recommended to insure proper slew operation. There is inrush current through the output MOSFET and the magnitude of the inrush current depends on the output capacitor, the bigger the C_{OUT} the higher the inrush current. There are no ESR or capacitor type requirement.

Enable

The EN pin is compatible with CMOS logic voltage levels. It requires at least 0.1 V or below to fully shut down the device and 1.5 V or above to fully turn on the device.

The EN pin can withstand voltage higher than V_{IN} .

Protection Against Reverse Voltage Condition

SiP32501 can block the output current from going to the input in case where the output voltage is higher than the input voltage when the main switch is off.

Thermal Considerations

This device is designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.2 A as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package and the PCB layout. To obtain the highest power dissipation (and a thermal resistance of 170 $^{\circ}$ C/W) the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature, T_J (max.) = 125 $^{\circ}$ C, the junction-to-ambient thermal resistance, θ_{JA} = 170 $^{\circ}$ C/W, and the ambient temperature, T_A , which may be formulaically expressed as:

$$P(\text{max.}) = \frac{T_J(\text{max.}) - T_A}{\theta_{JA}} = \frac{125 - T_A}{170}$$

It then follows that, assuming an ambient temperature of 70 $^{\circ}$ C, the maximum power dissipation will be limited to about 323 mW.

So long as the load current is below the 1.2 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the $R_{DS(on)}$ at the ambient temperature.

As an example let us calculate the worst case maximum load current at T_A = 70 $^{\circ}$ C. The worst case $R_{DS(on)}$ at 25 $^{\circ}$ C is 82 m Ω . The $R_{DS(on)}$ at 70 $^{\circ}$ C can be extrapolated from this data using the following formula:

$$R_{DS(on)}(\text{at } 70^{\circ}\text{C}) = R_{DS(on)}(\text{at } 25^{\circ}\text{C}) \times (1 + T_C \times \Delta T)$$

Where T_C is 4100 ppm/ $^{\circ}$ C. Continuing with the calculation we have

$$R_{DS(on)}(\text{at } 70^{\circ}\text{C}) = 82 \text{ m}\Omega \times (1 + 0.0041 \times (70^{\circ}\text{C} - 25^{\circ}\text{C})) = 97.1 \text{ m}\Omega$$

The maximum current limit is then determined by

$$I_{LOAD}(\text{max.}) < \sqrt{\frac{P(\text{max.})}{R_{DS(on)}}}$$

which in this case is 1.82 A. Under the stated input voltage condition, if the 1.82 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

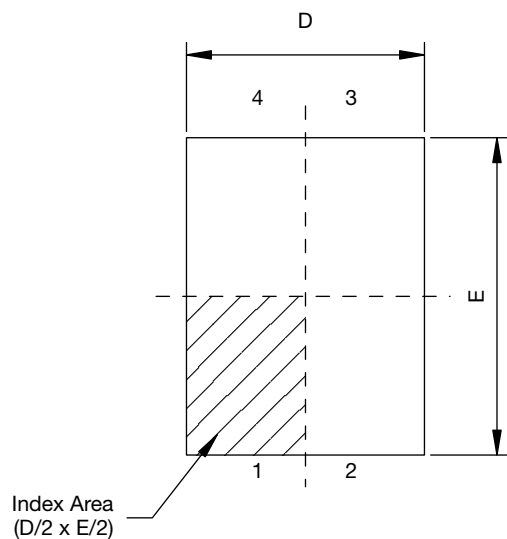
To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 1.2 A only as listed in the Absolute Maximum Ratings table.



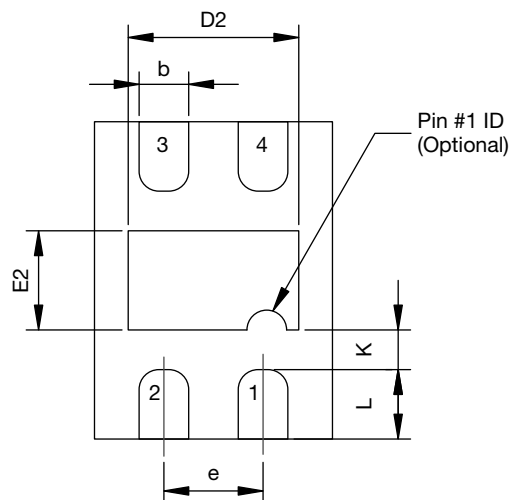
PRODUCT SUMMARY	
Part number	SiP32501
Description	0.9 V to 2.5 V, 66 m Ω , 9.8 μ s rise time, load switch
Configuration	Single
Slew rate time (μ s)	9.8
On delay time (μ s)	0.05
Input voltage min. (V)	0.9
Input voltage max. (V)	2.5
On-resistance at input voltage min. (m Ω)	69
On-resistance at input voltage max. (m Ω)	66
Quiescent current at input voltage min. (μ A)	5
Quiescent current at input voltage max. (μ A)	40
Output discharge (yes / no)	No
Reverse blocking (yes / no)	Yes
Continuous current (A)	1.2
Package type	TDFN4
Package size (W, L, H) (mm)	1.2 x 1.6 x 0.5
Status code	2
Product type	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable

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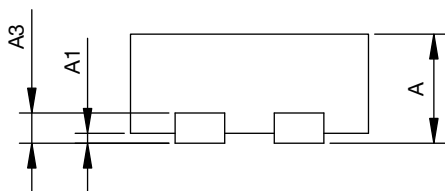
TDFN4 1.2 x 1.6 Case Outline



Top View



Bottom View



Side View

DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.45	0.55	0.60	0.017	0.022	0.024
A1	0.00	-	0.05	0.00	-	0.002
A3	0.15 REF. or 0.127 REF. ⁽¹⁾			0.006 or 0.005 ⁽¹⁾		
b	0.20	0.25	0.30	0.008	0.010	0.012
D	1.15	1.20	1.25	0.045	0.047	0.049
D2	0.81	0.86	0.91	0.032	0.034	0.036
e	0.50 BSC			0.020		
E	1.55	1.60	1.65	0.061	0.063	0.065
E2	0.45	0.50	0.55	0.018	0.020	0.022
K	0.25 typ.			0.010 typ.		
L	0.25	0.30	0.35	0.010	0.012	0.014
ECN: T16-0143-Rev. C, 18-Apr-16 DWG: 5995						

Note

⁽¹⁾ The dimension depends on the leadframe that assembly house used.



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